NSN 5962-01-353-9256

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Overall Lengtl	ւ։
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Between 1.435 inches and 1.485 inches

Overall Height:

0.281 inches

Body Length:

Between 1.435 inches and 1.485 inches

Body Width:

Between 0.515 inches and 0.599 inches

Body Height:

Between 0.140 inches and 0.180 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and w/enable and bidirectional and high impedance

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

25 input

Criticality Code Justification:

Feat

Current Rating Per Characteristic:

50.00 milliamperes reverse current, dc blank

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

34.00 nanoseconds propagation delay time, high to low level output and 34.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Eeprom

Special Features:

Nuclear hardness critical item

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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